



### 1.5MHZ, 1A STEP-DOWN DC-DC BUCK CONVERTER

### **Description**

The AP3428/A is a 1A step-down DC-DC converter. At heavy load, the constant-frequency PWM control performs excellent stability and transient response. No external compensation components are required.

The AP3428/A supports a range of input voltages from 2.5V to 5.5V, allowing the use of a single Li+/Li-polymer cell, multiple Alkaline/NiMH cell, and other standard power sources. The output voltage is adjustable from 0.6V to the input voltage. The AP3428/A employs internal power switch and synchronous rectifier to minimize external part count and realize high efficiency. During shutdown, the input is disconnected from the output and the shutdown current is less than  $1\mu A$ . Other key features include over-temperature and short circuit protection, and under-voltage lockout to prevent deep battery discharge.

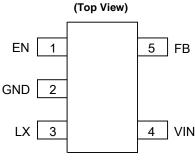
The AP3428/A delivers 1A maximum output current while consuming only  $40\mu A$  of no-load quiescent current. Ultra-low  $R_{DS(ON)}$  integrated MOSFETs and 100% duty cycle operation make the AP3428/A an ideal choice for high output voltage, high current applications which require a low dropout threshold. Pulse skip mode allows to maintain high efficiency at light-load conditions.

The AP3428/A is available in TSOT25, U-DFN2020-6 (Type J) packages.

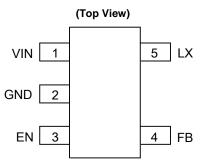
### **Features**

- Output Current: Up to 1A
- Output Voltage: 0.6V to VIN
- Input Voltage: 2.5V to 5.5V
- 0.6V Reference Voltage with ±2% Precision
- 40µA (typ) No Load Quiescent Current
- Shutdown Current: <1µA</li>
- 100% Duty Cycle Operation
- 1.5MHz Switching Frequency
- Internal Soft Start
- No External Compensation Required
- Current Limit Protection
- Thermal Shutdown
- TSOT25, U-DFN2020-6 (Type J) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

### **Pin Assignments**

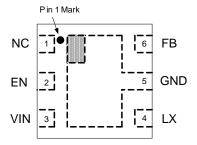


TSOT25 for AP3428



TSOT25 for AP3428A

### (Top View)



U-DFN2020-6 (Type J)

## **Applications**

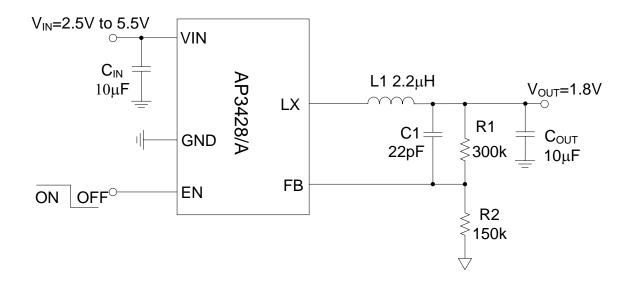
- Post DC-DC Voltage Regulation
- Set Top Boxes
- Notebook Computer
- PAD

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



# **Typical Applications Circuit**

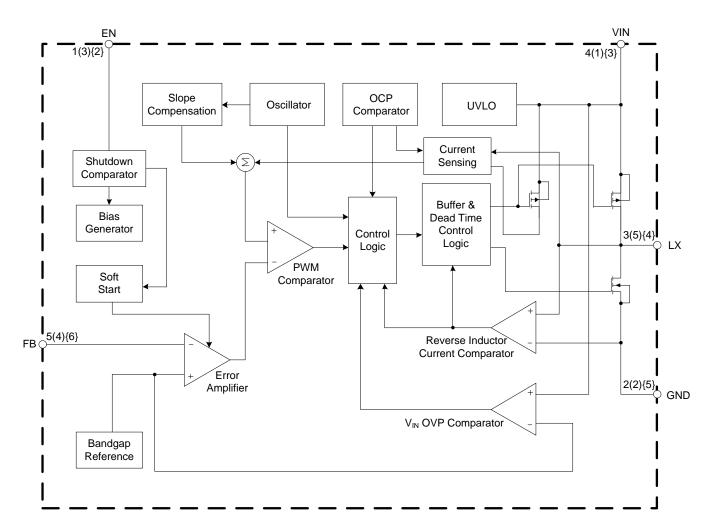


## **Pin Descriptions**

Pin Number		Pin		
TSOT25 for AP3428	TSOT25 for AP3428A	U-DFN2020-6 (Type J)	Name	Function
1	3	2	EN	Enable control input. Force this pin voltage above 1.5V enables the chip, and below 0.4V shuts down the device.
2	2	5	GND	Ground pin
3	5	4	LX	The drains of the internal main and synchronous power MOSFET.
4	1	3	VIN	Bias supply. Chip main power supply pin
5	4	6	FB	Feedback voltage to internal error amplifier, the threshold voltage is 0.6V.
_	_	1	NC	NC



## **Functional Block Diagram**



A: TSOT25 for AP3428 (B): TSOT25 for AP3428A {C}: U-DFN2020-6 (Type J)



## **Absolute Maximum Ratings** (Note 4)

Symbol	Parameter	Ratii	Rating	
Vin	Input Voltage	-0.3 t	-0.3 to 6	
Ven	EN Pin Voltage	-0.3 to V	'in+0.3	V
		-0.3 to V	'IN+0.3	V
VLX	LX Pin Voltage	-3V to 7V	-3V to 7V (<40ns)	
V <sub>FB</sub>	Feedback Pin Voltage	-0.3 to V	'ın+0.3	V
		TSOT25	0.4	
P <sub>D</sub>	Power Dissipation (on PCB, T <sub>A</sub> = +25°C)	U-DFN2020-6 (Type J)	1.89	W
		TSOT25	220	
θја	Thermal Resistance (Junction to Ambient)	U-DFN2020-6 (Type J)	53	°C/W
		TSOT25	130	
θιс	θ <sub>JC</sub> Thermal Resistance (Junction to Case, Simulation)		25	°C/W
TJ	Operating Junction Temperature	+15	+155	
T <sub>STG</sub>	Storage Temperature	-55 to -	-55 to +150	
Vмм	ESD (Machine Model)	200	200	
Vнвм	ESD (Human Body Model)	200	2000	
V <sub>CDM</sub>	ESD (Charge Device Mode)	100	1000	

Note 4: Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to *Absolute Maximum Ratings* for extended periods can affect device reliability.

## **Recommended Operating Conditions**

Symbol	Parameter	Min	Мах	Unit
Vin	Supply Voltage	2.5	5.5	V
TJ	Junction Temperature Range	-40	+125	°C
TA	Operating Ambient Temperature	-40	+85	°C



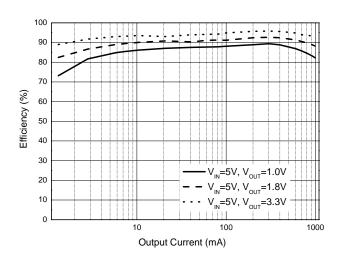
# $\textbf{Electrical Characteristics} \ (@T_A = +25^{\circ}C, \ V_{IN} = 5.0 \text{V}, \ V_{OUT} = 2.5 \text{V}, \ C_{OUT} = 10 \mu\text{F}, \ L = 2.2 \mu\text{H}, \ unless otherwise specified.})$

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Vin	Input Voltage Range	_	2.5	_	5.5	V
Vouт	Output Voltage Range	_	0.6	_	VIN	V
Ιq	Quiescent Current	V <sub>FB</sub> = 0.65V	_	40	_	μΑ
I <sub>SD</sub>	Shutdown Current	V <sub>EN</sub> = 0V	_	0.1	1	μΑ
V <sub>FB</sub>	Regulated Feedback Voltage	_	0.588	0.6	0.612	V
lfB	FB Leakage Current	V <sub>FB</sub> = 1V	_	_	0.2	μΑ
Ішм	Peak Inductor Current	_	1.3	_	_	А
fosc	Oscillator Frequency	_	_	1.5	_	MHz
_	Drain-Source On-State	I <sub>SW</sub> = 100mA High Side	_	250	_	mΩ
RDS(ON)	Resistance	Isw = 100mA Low Side	_	170	_	mΩ
Rdisch	Output Discharge Switch On Resister	_	_	2.1	_	kΩ
VENH	EN Threshold High	_	1.5	_	_	V
V <sub>ENL</sub>	EN Threshold Low	_	_	_	0.4	V
len	EN Leakage Current	VIN = VEN = 5V	-1.0	_	1.0	μΑ
Vuvlo	Input UVLO Threshold	_	_	2.4	2.7	V
VHYS	UVLO Hysteresis	_	_	0.1	_	V
Тотр	Over Temperature Protection	_	_	+160	_	°C
Тотн	OTP Hysteresis	_	_	+15	_	°C
tss	Soft-Start Time	_	_	2	_	ms

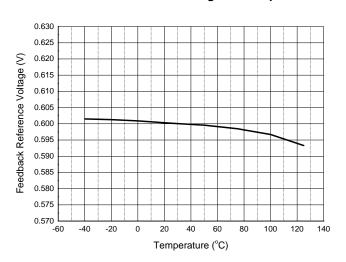


## Performance Characteristics (@ $T_A = +25$ °C, $V_{IN} = 5V$ , $V_{OUT} = 1.8V$ , unless otherwise specified.)

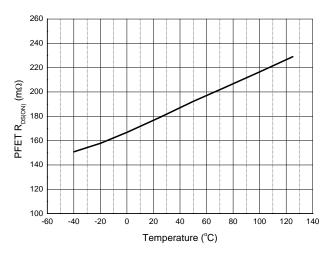
#### **Efficiency vs. Load Current**



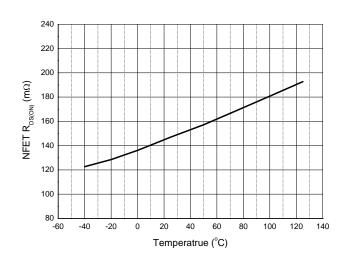
### Feedback Reference Voltage vs. Temperature



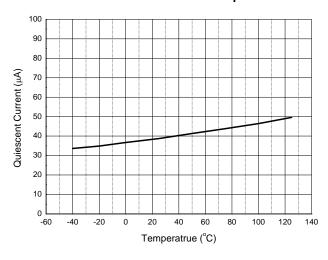
### PFET Drain-Source On-State Resistance vs. Temperature



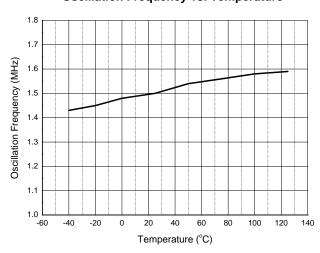
### NFET Drain-Source On-State Resistance vs. Temperature



### **Quiescent Current vs. Temperature**



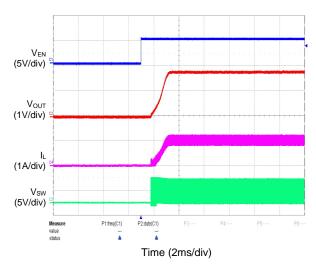
### Oscillation Frequency vs. Temperature



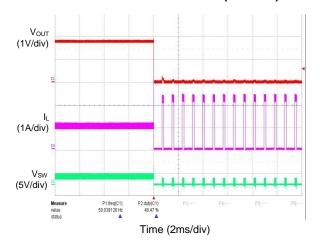


### Performance Characteristics (@T<sub>A</sub> = +25°C, V<sub>IN</sub> = 5V, V<sub>OUT</sub> = 1.8V, unless otherwise specified.) (continued)

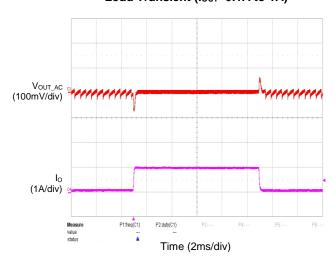
### Enable Turn On Characteristic (Iout = 1A)



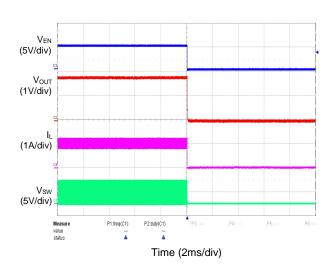
### **Short Current Protection (Iout = 1A)**



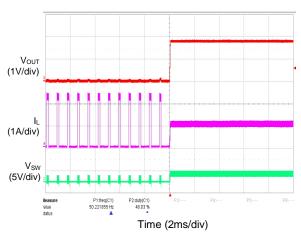
### Load Transient (Iout=0.1A to 1A)



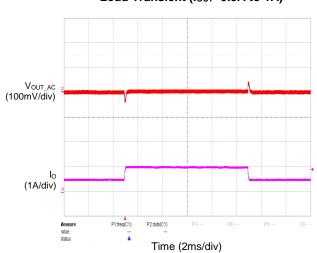
### Enable Turn Off Characteristic (Iout = 1A)



### SCP Recovery (Iout = 1A)



### Load Transient (Iout=0.5A to 1A)





### **Application Information**

Typical application circuit is shown in the *Typical Applications Circuit* and for the circuit parameters setting please refers to the following descriptions.

#### **Under Voltage Lockout (UVLO) Circuit**

When the  $V_{IN}$  drops lower than the UVLO detector threshold, the UVLO circuit starts to operate,  $V_{REF}$  stops, and high-side switch and low-side switch built-in switch transistors turn "OFF". As a result,  $V_{OUT}$  drops according to the  $C_{OUT}$  capacitance value and the load. When the  $V_{IN}$  is rising higher than UVLO released voltage, the IC will restart the operation.

#### **Short Circuit Protection and Recovery**

When the AP3428/A output node is shorted to GND that VFB drops under 0.42V, AP3428/A will enter hiccup mode to protect itself. If short circuit is removed, and VFB rises over 0.42V, the AP3428/A recovers to normal operation again. If the AP3428/A reaches OCP threshold while short circuit, the AP3428/A will enter cycle by cycle current limit mode until the current under OCP threshold.

#### **Over Temperature Protection**

The internal thermal temperature protection circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When the junction temperature exceeds +160°C, it shuts down the internal control circuit and switching power MOSFET. The AP3428/A will restart automatically under the control of soft start circuit when the junction temperature decreases to +145°C.

#### **Setting the Output Voltage**

The output voltage can be adjusted from 1 to 5V using an external resistor divider. Table 1 shows a list of resistor selections for common output voltages. Resistor R1 is selected based on a design tradeoff between efficiency and output voltage accuracy. For high values of R1 there is less current consumption in the feedback network. However the tradeoff is output voltage accuracy due to the bias current in the error amplifier. R1 can be determined by the following equation. Meanwhile, the input capacitor should close to IC for preventing unexpected influences.

$$R1 = R2 \cdot \left(\frac{Vout}{0.6} - 1\right)$$

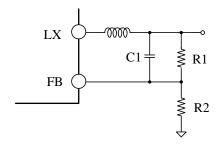


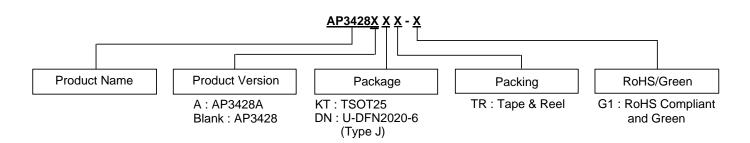
Figure 1. Feedback Divider Network

Out Voltage	R1	R2	C1
1.0V	91kΩ	120kΩ	22pF
1.2V	100kΩ	100kΩ	22pF
1.5V	150kΩ	100kΩ	22pF
1.8V	300kΩ	150kΩ	22pF
2.5V	380kΩ	120kΩ	22pF
2.8V	440kΩ	120kΩ	22pF
3.3V	430kΩ	100kΩ	22pF

**Table 1. Resistor Selection for Common Output** 



## **Ordering Information**



Package	Temperature Range	Part Number	Marking ID	Packing
TSOT25	-40 to +85°C	AP3428AKTTR-G1	L2J	3000/Tape & Reel
TSOT25	-40 to +85°C	AP3428KTTR-G1	L2H	3000/Tape & Reel
U-DFN2020-6 (Type J)	-40 to +85°C	AP3428DNTR-G1	CQ	3000/Tape & Reel



## **Marking Information**

### (1) TSOT25 for AP3428

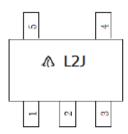




First Line: Logo and Marking ID

### (2) TSOT25 for AP3428A

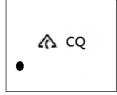
### (Top View)



First Line: Logo and Marking ID

### (3) U-DFN2020-6 (Type J)

### (Top View)



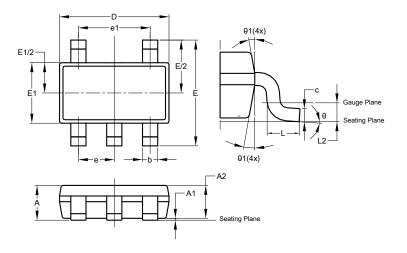
First Line: Logo and Marking ID



## **Package Outline Dimensions**

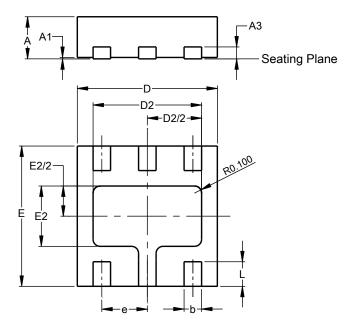
Please see http://www.diodes.com/package-outlines.html for the latest version.

### (1) Package Type: TSOT25



	TSOT25				
Dim	Min Max Typ				
Α	-	1.00	-		
A1	0.01	0.10	-		
A2	0.84	0.90	-		
b	0.30	0.45	-		
C	0.12	0.12 0.20 -			
D	-	2.90			
Е	-	-	2.80		
E1	-	-	1.60		
е	(	0.95 BS	O		
e1		1.90 BS	O		
L	0.30	0.50	-		
L2	0.25 BSC				
θ	0°	8°	4°		
θ1	4°	12°	-		
All Dimensions in mm					

### (2) Package Type: U-DFN2020-6 (Type J)



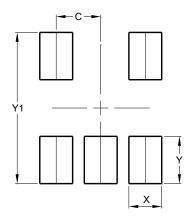
	U-DFN2020-6					
	(Type J)					
Dim	Min	Max	Тур			
Α	0.50	0.60				
A1	0.00	0.05	0.03			
A3			0.203			
b	0.20	0.30	0.25			
D	1.95	2.075	2.00			
D2	1.45	1.65	1.55			
E	1.95	2.075	2.00			
E2	0.76 0.96 0.86					
е	0.65 BSC					
L	0.30	0.40	0.35			
All Dimensions in mm						



### **Suggested Pad Layout**

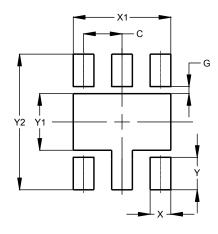
Please see http://www.diodes.com/package-outlines.html for the latest version.

### (1) Package Type: TSOT25



Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
Y1	3.199

### (2) Package Type: U-DFN2020-6 (Type J)



Dimensions	Value
Dilliensions	(in mm)
С	0.650
G	0.120
Х	0.350
X1	1.650
Y	0.550
Y1	0.960
Y2	2.300

### **Mechanical Data**

#### TSOT25

- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.014 grams (Approximate)

### U-DFN2020-6 (Type J)

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leads, Solderable per MIL-STD-202, Method 208 (4)
- Weight: 0.007 grams (Approximate)



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